

# TOSHIBA MOS MEMORY PRODUCT

262,144 WORDS × 4 BIT DYNAMIC RAM  
SILICON GATE CMOS

TC514258P/J/Z-85, TC514258P/J/Z-10  
TC514258P/J/Z-12

## DESCRIPTION

The TC514258P/J/Z is the new generation dynamic RAM organized 262,144 words by 4 bit. The TC514258P/J/Z utilizes TOSHIBA's CMOS Silicon gate process technology as well as advanced circuit techniques to provide wide operating margins, both internally and to the system user. Multiplexed address inputs permit the TC514258P/J/Z to be packaged in a standard 20 pin plastic DIP and 20/26 pin plastic SOJ and 20/19 pin plastic ZIP. The package size provides high system bit densities and is compatible with widely available automated testing and insertion equipment. System oriented features include single power supply of 5V±10% tolerance, direct interfacing capability with high performance logic families such as Schottky TTL.

## FEATURES

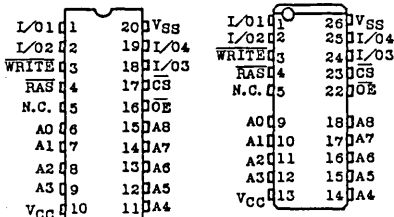
- 262,144 words by 4 bit organization
- Fast access time and cycle time
- Low Power
  - 413mW MAX. Operating (TC514258P/J/Z-85)
  - 358mW MAX. Operating (TC514258P/J/Z-10)
  - 303mW MAX. Operating (TC514258P/J/Z-12)
  - 5.5mW MAX. Standby
- Outputs unlatched at cycle end allows two-dimensional chip selection
- Read-Modify-Write,  $\overline{CS}$  before  $\overline{RAS}$  refresh,  $\overline{RAS}$ -only refresh, Hidden refresh and Static Column Mode capability
- All inputs and outputs TTL compatible
- 512 refresh cycles/8ms
- Package
  - Plastic DIP: TC514258P
  - Plastic SOJ: TC514258J
  - Plastic ZIP: TC514258Z

	TC514258P/J/Z-85-10-12		
$t_{RAC}$ $\overline{RAS}$ Access Time	85ns	100ns	120ns
$t_{AA}$ Column Address Access Time	45ns	50ns	60ns
$t_{CAC}$ $\overline{CS}$ Access Time	30ns	30ns	35ns
$t_{RC}$ Cycle Time	165ns	190ns	220ns
$t_{SC}$ Static Column Mode Cycle Time	50ns	55ns	65ns

- Single power supply of 5V±10% with a built-in  $V_{BB}$  generator

## PIN CONNECTION (TOP VIEW)

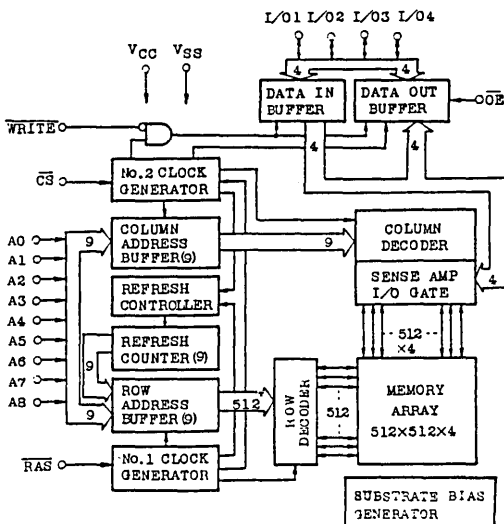
- Plastic DIP
- Plastic SOJ
- Plastic ZIP



## PIN NAMES

AO ~ A8	Address Inputs
RAS	Row Address Strobe
CS	Chip Select
WRITE	Read/Write Input
OE	Output Enable
I/O1 ~ I/O4	Data Input/Output
VCC	Power (+5V)
VSS	Ground
N.C.	No Connection

## BLOCK DIAGRAM



# TC514258P/J/Z-85, TC514258P/J/Z-10 TC514258P/J/Z-12

## ABSOLUTE MAXIMUM RATINGS

ITEM	SYMBOL	RATING	UNITS	NOTES
Input Voltage	V <sub>IN</sub>	-1 ~ 7	V	1
Output Voltage	V <sub>OUT</sub>	-1 ~ 7	V	1
Power Supply Voltage	V <sub>CC</sub>	-1 ~ 7	V	1
Operating Temperature	T <sub>OPR</sub>	0 ~ 70	°C	1
Storage Temperature	T <sub>STG</sub>	-55 ~ 150	°C	1
Soldering Temperature · Time	T <sub>SOLDER</sub>	260 · 10	°C · sec	1
Power Dissipation	P <sub>D</sub>	600	mW	1
Short Circuit Output Current	I <sub>OUT</sub>	50	mA	1

## RECOMMENDED DC OPERATING CONDITIONS (T<sub>a</sub>=0 ~ 70°C)

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT	NOTES
V <sub>CC</sub>	Supply Voltage	4.5	5.0	5.5	V	2
V <sub>IH</sub>	Input High Voltage	2.4	-	6.5	V	2
V <sub>IL</sub>	Input Low Voltage	-1.0	-	0.8	V	2

## DC ELECTRICAL CHARACTERISTICS (V<sub>CC</sub>=5V±10%, T<sub>a</sub>=0 ~ 70°C)

SYMBOL	PARAMETER	MIN.	UNIT	UNITS	NOTES	
I <sub>CC1</sub>	OPERATING CURRENT Average Power Supply Operating Current (RAS, CS, Address Cycling: t <sub>RC</sub> =t <sub>RC</sub> MIN.)	TC514258P/J/Z-85	-	75	mA	3,4
		TC514258P/J/Z-10	-	65		
		TC514258P/J/Z-12	-	55		
I <sub>CC2</sub>	STANDBY CURRENT Power Supply Standby Current (RAS=CS=V <sub>IH</sub> )	-	2	mA		
I <sub>CC3</sub>	RAS ONLY REFRESH CURRENT Average Power Supply Current, RAS Only Mode (RAS Cycling, CS=V <sub>IH</sub> : t <sub>RC</sub> =t <sub>RC</sub> MIN.)	TC514258P/J/Z-85	-	75	mA	3
		TC514258P/J/Z-10	-	65		
		TC514258P/J/Z-12	-	55		
I <sub>CC4</sub>	STATIC COLUMN MODE CURRENT Average Power Supply Current, Static Column Mode (RAS=CS=V <sub>IL</sub> , Address Cycling: t <sub>SC</sub> =t <sub>SC</sub> MIN.)	TC514258P/J/Z-85	-	75	mA	3,4
		TC514258P/J/Z-10	-	65		
		TC514258P/J/Z-12	-	55		
I <sub>CC5</sub>	STANDBY CURRENT Power Supply Standby Current (RAS=CS=V <sub>CC</sub> -0.2V)	-	1	mA		
I <sub>CC6</sub>	CS BEFORE RAS REFRESH CURRENT Average Power Supply Current, CS Before RAS Mode (RAS, CS Cycling: t <sub>RC</sub> =t <sub>RC</sub> MIN.)	TC514258P/J/Z-85	-	75	mA	3
		TC514258P/J/Z-10	-	65		
		TC514258P/J/Z-12	-	55		
I <sub>I(L)</sub>	INPUT LEAKAGE CURRENT Input Leakage Current, any input (0V ≤ V <sub>IN</sub> ≤ 6.5V, All Other Pins Not Under Test = 0V)	-10	10	μA		
I <sub>O(L)</sub>	OUTPUT LEAKAGE CURRENT (DOUT is disable, 0V ≤ V <sub>OUT</sub> ≤ 5.5V)	-10	10	μA		
V <sub>OH</sub>	OUTPUT LEVEL Output "H" Level Voltage (I <sub>OUT</sub> =-5mA)	2.4	-	V		
V <sub>OL</sub>	OUTPUT LEVEL Output "L" Level Voltage (I <sub>OUT</sub> =4.2mA)	-	0.4	V		

# TC514258P/J/Z-85, TC514258P/J/Z-10 TC514258P/J/Z-12

## ELECTRICAL CHARACTERISTICS AND RECOMMENDED AC OPERATING CONDITIONS

(V<sub>CC</sub>=5V±10%, T<sub>a</sub>=0~70°C) (Notes 5, 6, 7)

SYMBOL	PARAMETER	TC514258P/J/Z-85		TC514258P/J/Z-10		TC514258P/J/Z-12		UNIT	NOTES
		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
t <sub>RC</sub>	Random Read or Write Cycle Time	165	-	190	-	220	-	ns	
t <sub>RMW</sub>	Read-Modify-Write Cycle Time	225	-	255	-	295	-	ns	
t <sub>SC</sub>	Static Column Mode Cycle Time	50	-	55	-	65	-	ns	
t <sub>SRMW</sub>	Static Column Mode Read-Modify-Write Cycle Time	110	-	115	-	135	-	ns	
t <sub>RAC</sub>	Access Time from $\overline{\text{RAS}}$	-	85	-	100	-	120	ns	8,13
t <sub>CAC</sub>	Access Time from $\overline{\text{CS}}$	-	30	-	30	-	35	ns	8,13
t <sub>AA</sub>	Access Time from Column Address	-	45	-	50	-	60	ns	8,14
t <sub>ALW</sub>	Access Time from Last Write	-	85	-	95	-	115	ns	8,15
t <sub>CLZ</sub>	$\overline{\text{CS}}$ to Output in Low-Z	5	-	5	-	5	-	ns	8
t <sub>OFF</sub>	Output Buffer Turn-off Delay	0	30	0	30	0	35	ns	9
t <sub>AOH</sub>	Output Data Hold Time from Column Address	5	-	5	-	5	-	ns	
t <sub>OW</sub>	Output Data Enable Time from $\overline{\text{WRITE}}$	-	30	-	30	-	35	ns	
t <sub>T</sub>	Transition Time (Rise and Fall)	3	50	3	50	3	50	ns	7
t <sub>RP</sub>	$\overline{\text{RAS}}$ Precharge Time	70	-	80	-	90	-	ns	
t <sub>RAS</sub>	$\overline{\text{RAS}}$ Pulse Width	85	10,000	100	10,000	120	10,000	ns	
t <sub>RASC</sub>	$\overline{\text{RAS}}$ Pulse Width (Static Column Mode)	85	100,000	100	100,000	120	100,000	ns	
t <sub>RSH</sub>	$\overline{\text{CS}}$ to $\overline{\text{RAS}}$ Hold Time	30	-	30	-	35	-	ns	
t <sub>CSH</sub>	$\overline{\text{RAS}}$ to $\overline{\text{CS}}$ Hold Time	85	-	100	-	120	-	ns	
t <sub>CS</sub>	$\overline{\text{CS}}$ Pulse Width	30	10,000	30	10,000	35	10,000	ns	
t <sub>CSC</sub>	$\overline{\text{CS}}$ Pulse Width (Static Column Mode)	30	100,000	30	100,000	35	100,000	ns	
t <sub>RCD</sub>	$\overline{\text{RAS}}$ to $\overline{\text{CS}}$ Delay Time	25	55	25	70	25	85	ns	13
t <sub>RAD</sub>	$\overline{\text{RAS}}$ to Column Address Delay Time	20	40	20	50	20	60	ns	14
t <sub>CRP</sub>	$\overline{\text{CS}}$ to $\overline{\text{RAS}}$ Precharge Time	10	-	10	-	10	-	ns	
t <sub>CPN</sub>	$\overline{\text{CS}}$ Precharge Time	15	-	15	-	20	-	ns	
t <sub>CP</sub>	$\overline{\text{CS}}$ Precharge Time (Static Column Mode)	10	-	10	-	15	-	ns	
t <sub>ASR</sub>	Row Address Set-up Time	0	-	0	-	0	-	ns	
t <sub>RAH</sub>	Row Address Hold Time	15	-	15	-	15	-	ns	
t <sub>ASC</sub>	Column Address Set-up Time	0	-	0	-	0	-	ns	
t <sub>CAH</sub>	Column Address Hold Time	20	-	20	-	25	-	ns	
t <sub>AWR</sub>	Write Address Hold Time Referenced to $\overline{\text{RAS}}$	65	-	75	-	90	-	ns	
t <sub>AR</sub>	Column Address Hold Time Referenced to $\overline{\text{RAS}}$	100	-	115	-	140	-	ns	
t <sub>RAL</sub>	Column Address to $\overline{\text{RAS}}$ Lead Time	45	-	50	-	60	-	ns	
t <sub>AH</sub>	Column Address Hold Time Referenced to $\overline{\text{RAS}}$ Rise	10	-	10	-	15	-	ns	16
t <sub>LWAD</sub>	Last Write to Column Address Delay Time	25	40	25	45	30	55	ns	17

**TC514258P/J/Z-85, TC514258P/J/Z-10  
TC514258P/J/Z-12**

SYMBOL	PARAMETER	TC514258P/J/Z-85		TC514258P/J/Z-10		TC514258P/J/Z-12		UNIT	NOTES
		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
t <sub>AHLW</sub>	Last Write to Column Address Hold Time	85	-	95	-	115	-	ns	
t <sub>RCS</sub>	Read Command Set-up Time Referenced to $\overline{CS}$	0	-	0	-	0	-	ns	
t <sub>RCH</sub>	Read Command Hold Time Referenced to $\overline{CS}$	0	-	0	-	0	-	ns	10
t <sub>RRH</sub>	Read Command Hold Time Referenced to $\overline{RAS}$	0	-	0	-	0	-	ns	10
t <sub>WH</sub>	Write Command Hold Time (Output Data Disable)	0	-	0	-	0	-	ns	12
t <sub>WCR</sub>	Write Command Hold Time Referenced to $\overline{RAS}$	65	-	75	-	90	-	ns	
t <sub>WP</sub>	$\overline{WRITE}$ Pulse Width	20	-	20	-	25	-	ns	
t <sub>WI</sub>	$\overline{WRITE}$ Inactive Time	10	-	10	-	15	-	ns	
t <sub>RWL</sub>	$\overline{WRITE}$ Command to $\overline{RAS}$ Lead Time	20	-	25	-	30	-	ns	
t <sub>CWL</sub>	$\overline{WRITE}$ Command to $\overline{CS}$ Lead Time	20	-	25	-	30	-	ns	
t <sub>DS</sub>	Data-In Set-Up Time	0	-	0	-	0	-	ns	11
t <sub>DH</sub>	Data-In Hold Time	20	-	20	-	25	-	ns	11
t <sub>DHR</sub>	Data-In Hold Time Referenced to $\overline{RAS}$	65	-	75	-	90	-	ns	
t <sub>REF</sub>	Refresh Period	-	8	-	8	-	8	ms	
t <sub>WS</sub>	$\overline{WRITE}$ Command Set-Up Time (Output Data Disable)	0	-	0	-	0	-	ns	12
t <sub>CWD</sub>	$\overline{CS}$ to $\overline{WRITE}$ Delay Time (READ-MODIFY-WRITE CYCLE)	65	-	65	-	75	-	ns	12
t <sub>RWD</sub>	$\overline{RAS}$ to $\overline{WRITE}$ Delay Time (READ-MODIFY-WRITE CYCLE)	120	-	135	-	160	-	ns	12
t <sub>AWD</sub>	Column Address to $\overline{WRITE}$ Delay Time	80	-	85	-	100	-	ns	12
t <sub>CSR</sub>	$\overline{CS}$ Set-Up Time ( $\overline{CS}$ before $\overline{RAS}$ )	10	-	10	-	10	-	ns	
t <sub>CHR</sub>	$\overline{CS}$ Hold Time ( $\overline{CS}$ before $\overline{RAS}$ )	30	-	30	-	30	-	ns	
t <sub>RPC</sub>	$\overline{RAS}$ to $\overline{CS}$ Precharge Time	0	-	0	-	0	-	ns	
t <sub>CPT</sub>	$\overline{CS}$ Precharge Time ( $\overline{CS}$ before $\overline{RAS}$ counter Test Cycle)	50	-	50	-	60	-	ns	
t <sub>ROH</sub>	$\overline{RAS}$ Hold Time Referenced to $\overline{OE}$	20	-	20	-	20	-	ns	
t <sub>OE A</sub>	$\overline{OE}$ Access Time	-	30	-	35	-	45	ns	
t <sub>OE D</sub>	$\overline{OE}$ to Data Delay	25	-	25	-	30	-	ns	
t <sub>OE Z</sub>	Output Buffer turn off Delay Time from $\overline{OE}$	0	25	0	25	0	30	ns	9
t <sub>OE H</sub>	$\overline{OE}$ Command Hold Time	25	-	25	-	30	-	ns	

# TC514258P/J/Z-85, TC514258P/J/Z-10 TC514258P/J/Z-12

CAPACITANCE ( $V_{CC}=5V\pm 10\%$ ,  $f=1\text{MHz}$ ,  $T_a=0\sim 70^\circ\text{C}$ )

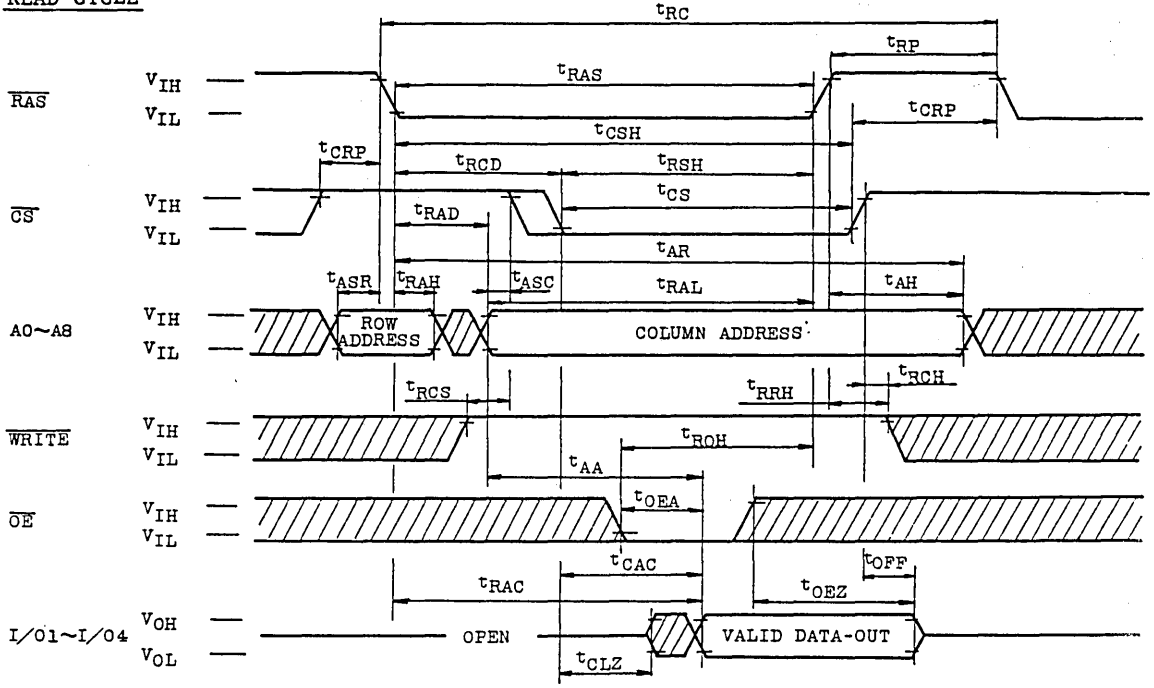
SYMBOL	PARAMETER	MIN.	MAX.	UNIT
C <sub>I1</sub>	Input Capacitance ( $A_0 \sim A_8$ )	-	5	pF
C <sub>I2</sub>	Input Capacitance ( $\overline{\text{RAS}}$ , $\overline{\text{CS}}$ , $\overline{\text{WRITE}}$ , $\overline{\text{OE}}$ )	-	7	
C <sub>O</sub>	Output Capacitance ( $I/O_1 \sim I/O_4$ )	-	7	

## NOTES:

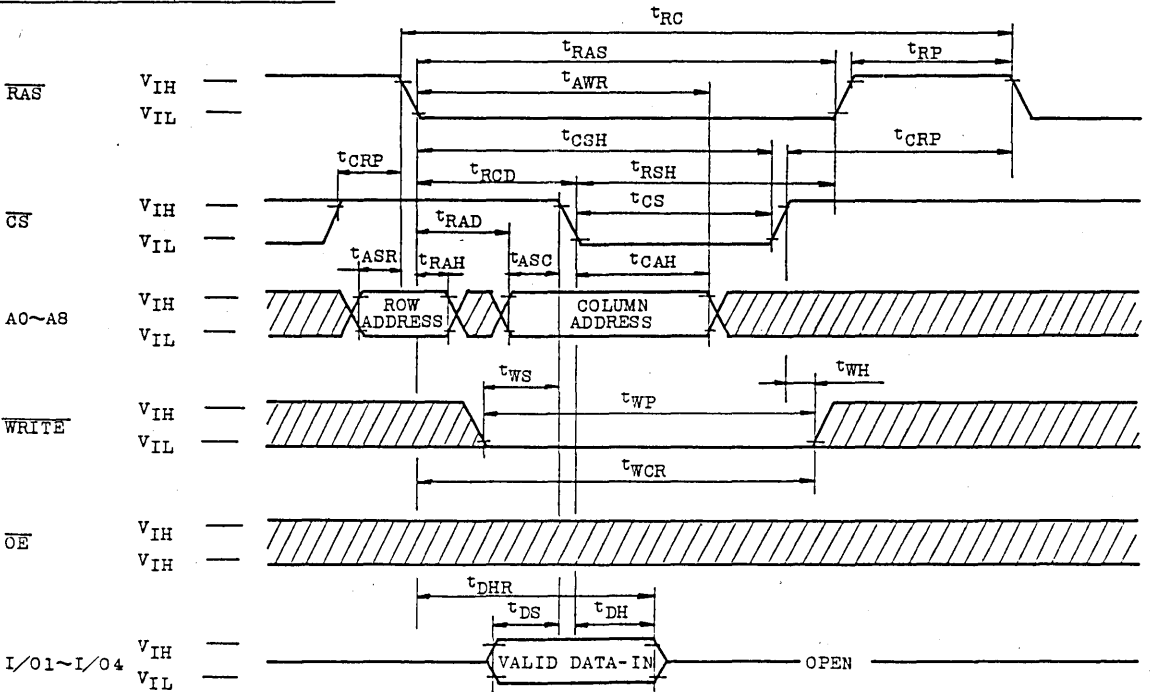
1. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device.
2. All voltage are referenced to  $V_{SS}$ .
3.  $I_{c1}$ ,  $I_{c3}$ ,  $I_{c4}$ ,  $I_{c6}$  depend on cycle rate.
4.  $I_{c1}$ ,  $I_{c4}$  depend on output loading. Specified values are obtained with the output open.
5. An initial pause of 200 $\mu\text{s}$  is required after power-up followed by 8  $\overline{\text{RAS}}$  cycles before proper device operation is achieved. In case of using internal refresh counter, a minimum of 8  $\overline{\text{CS}}$  Before  $\overline{\text{RAS}}$  initialization cycles instead of 8  $\overline{\text{RAS}}$  cycles are required.
6. AC measurements assume  $t_T=5\text{ns}$ .
7.  $V_{IH}(\text{min.})$  and  $V_{IL}(\text{max.})$  are reference levels for measuring timing of input signals.
8. Measured with a load equivalent to 2 TTL loads and 100pF.
9.  $t_{OFF}(\text{max.})$  and  $t_{OEZ}(\text{max.})$  define the time at which the output achieves the open circuit condition and is not referenced to output voltage levels.
10. Either  $t_{RCH}$  or  $t_{RRH}$  must be satisfied for a read cycle.
11. These parameters are referenced to  $\overline{\text{CS}}$  leading edge in early write cycles and to  $\overline{\text{WRITE}}$  leading edge in Read-Modify-Write cycles.
12.  $t_{WS}$ ,  $t_{WH}$ ,  $t_{RWD}$ ,  $t_{CWD}$  and  $t_{AWD}$  are not restrictive operating parameters. They are included the data sheet as electrical characteristics only. If  $t_{WS} \geq t_{WS}(\text{min.})$ , the cycle is an early write cycle and the data out pin will remain open circuit (high impedance) through the entire cycle; If  $t_{RWD} \geq t_{RWD}(\text{min.})$ ,  $t_{CWD} \geq t_{CWD}(\text{min.})$  and  $t_{AWD} \geq t_{AWD}(\text{min.})$ , the cycle is a Read-Modify-Write cycle and the data out will contain data read from the selected cell: If neither of the above sets of conditions is satisfied, the condition of the data out (at access time) is indeterminate.
13. Operation within the  $t_{RCD}(\text{max.})$  limit insures that  $t_{RAC}(\text{max.})$  can be met.  $t_{RCD}(\text{max.})$  is specified as a reference point only: If  $t_{RCD}$  is greater than the specified  $t_{RCD}(\text{max.})$  limit, then access time is controlled by  $t_{CAC}$ .
14. Operation within the  $t_{RAD}(\text{max.})$  limit insures that  $t_{RAC}(\text{max.})$  can be met.  $t_{RAD}(\text{max.})$  is specified as a reference point only: If  $t_{RAD}$  is greater than the specified  $t_{RAD}(\text{max.})$  limit, then access time is controlled by  $t_{AA}$ .
15. Operation within the  $t_{LWAD}(\text{max.})$  limit insures that  $t_{ALW}(\text{max.})$  can be met.  $t_{LWAD}(\text{max.})$  is specified as a reference point only: If  $t_{LWAD}$  is greater than the specified  $t_{LWAD}(\text{max.})$  limit, then access time is controlled exclusively by  $t_{AA}$ .
16.  $t_{AH}$  is the condition to latch column address when  $\overline{\text{RAS}}$  has risen up.

# TC514258P/J/Z-85, TC514258P/J/Z-10 TC514258P/J/Z-12

## READ CYCLE

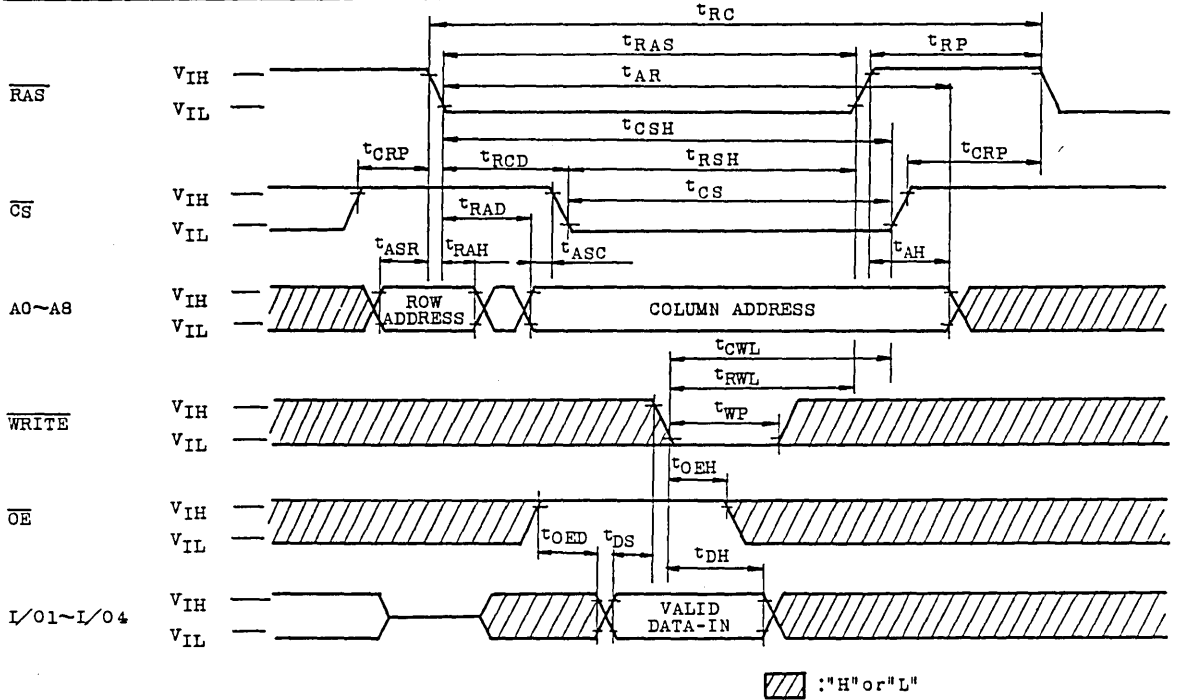


## WRITE CYCLE (EARLY WRITE)

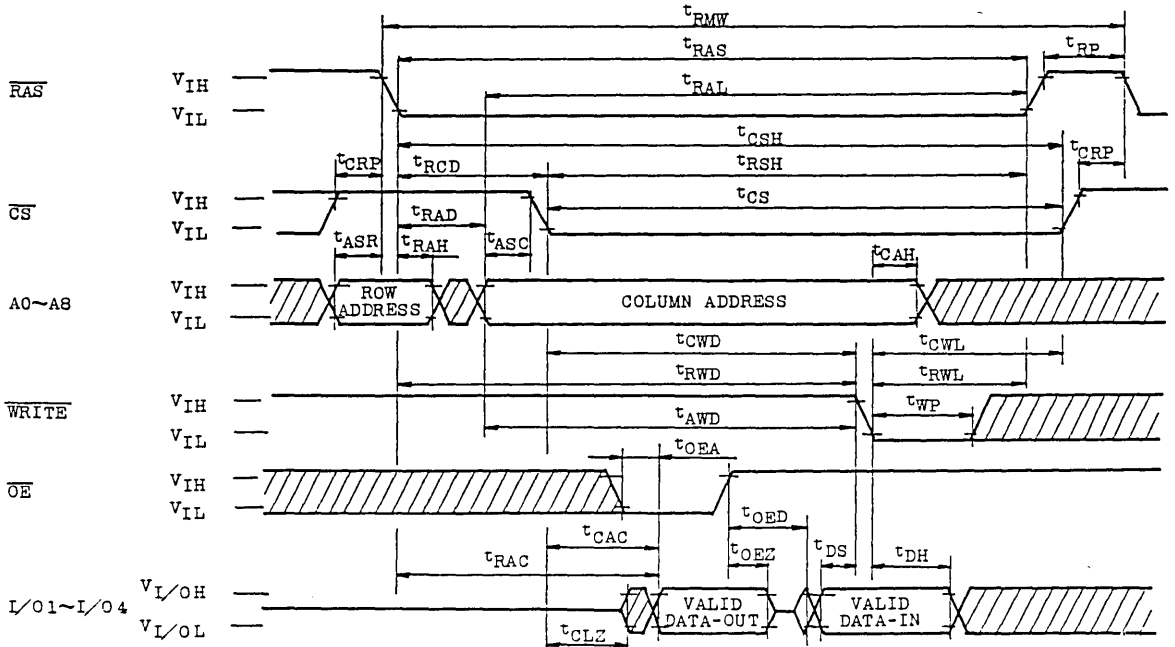


# TC514258P/J/Z-85, TC514258P/J/Z-10 TC514258P/J/Z-12

## WRITE CYCLE ( $\overline{OE}$ CONTROLLED WRITE)

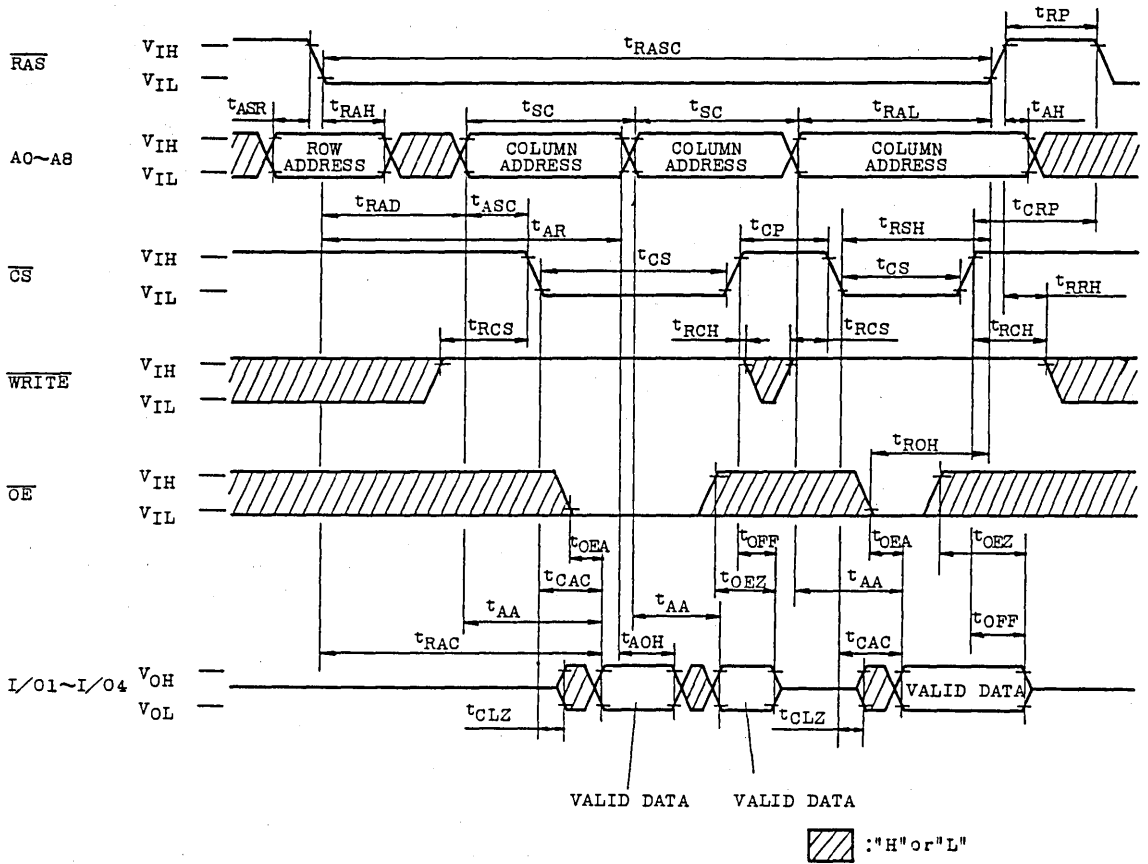


## READ-MODIFY-WRITE CYCLE



# TC514258P/J/Z-85, TC514258P/J/Z-10 TC514258P/J/Z-12

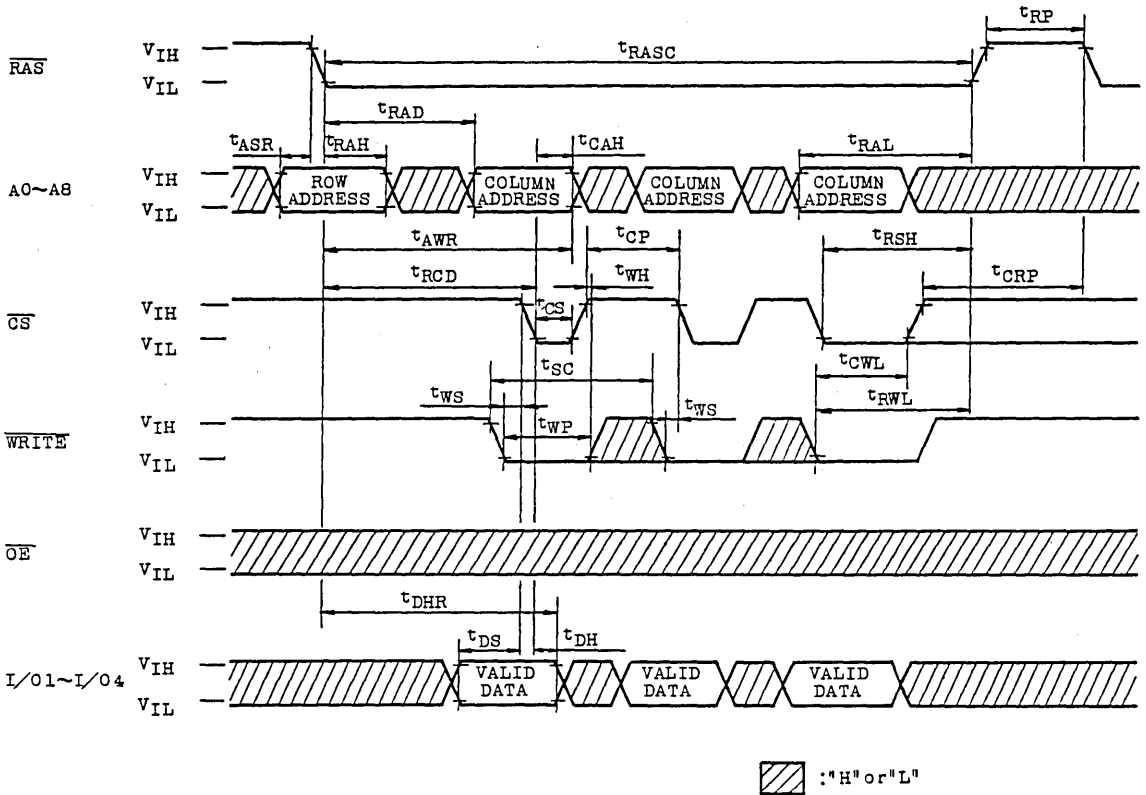
## STATIC COLUMN MODE READ CYCLE





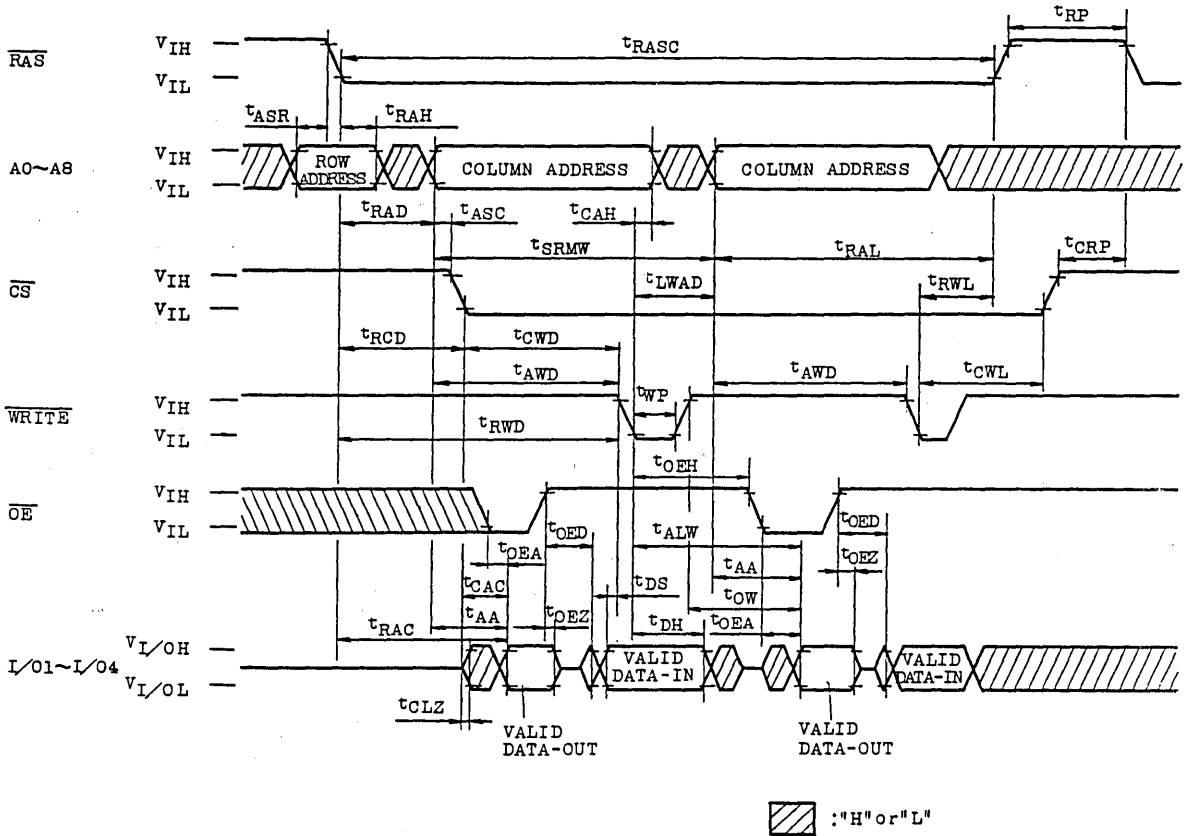
# TC514258P/J/Z-85, TC514258P/J/Z-10 TC514258P/J/Z-12

## STATIC COLUMN MODE WRITE CYCLE (EARLY WRITE)



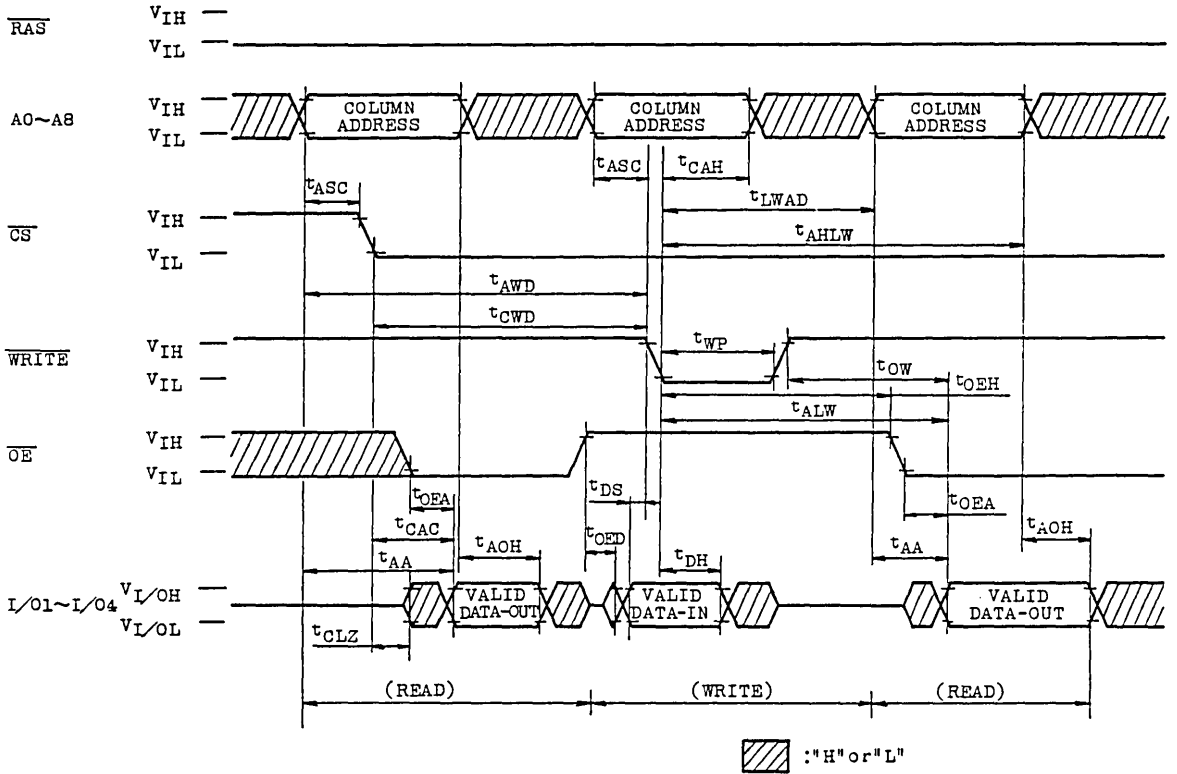
**TC514258P/J/Z-85, TC514258P/J/Z-10  
TC514258P/J/Z-12**

STATIC COLUMN MODE READ-MODIFY-WRITE CYCLE



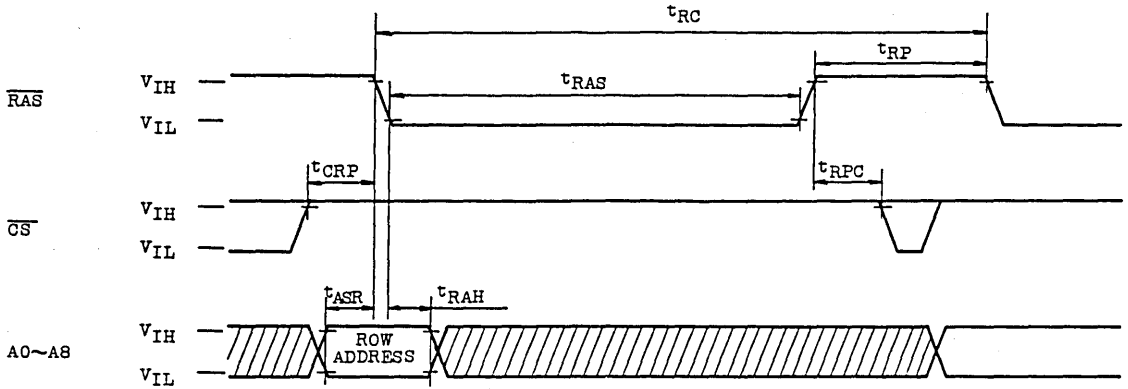
# TC514258P/J/Z-85, TC514258P/J/Z-10 TC514258P/J/Z-12

## STATIC COLUMN MODE READ/WRITE MIXED CYCLE



**TC514258P/J/Z-85, TC514258P/J/Z-10  
TC514258P/J/Z-12**

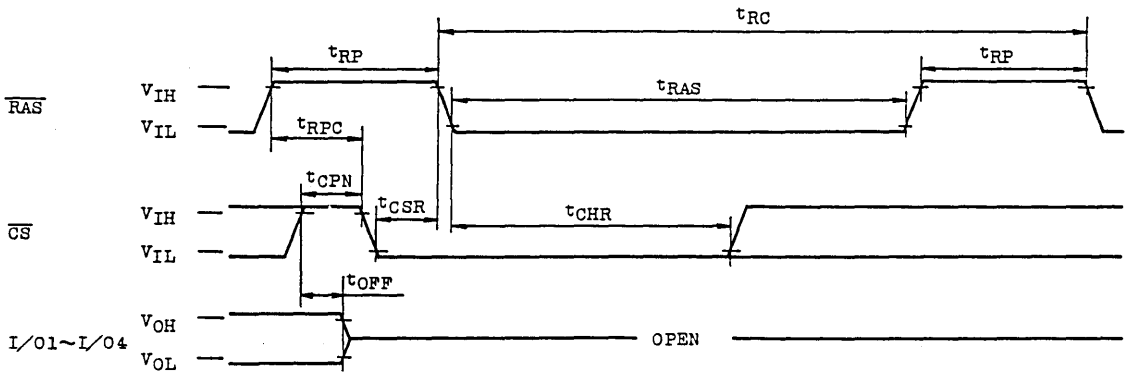
RAS ONLY REFRESH CYCLE



Notes:  $\overline{\text{WRITE}}$ ,  $\overline{\text{OE}}$  : "H" or "L"

: "H" or "L"

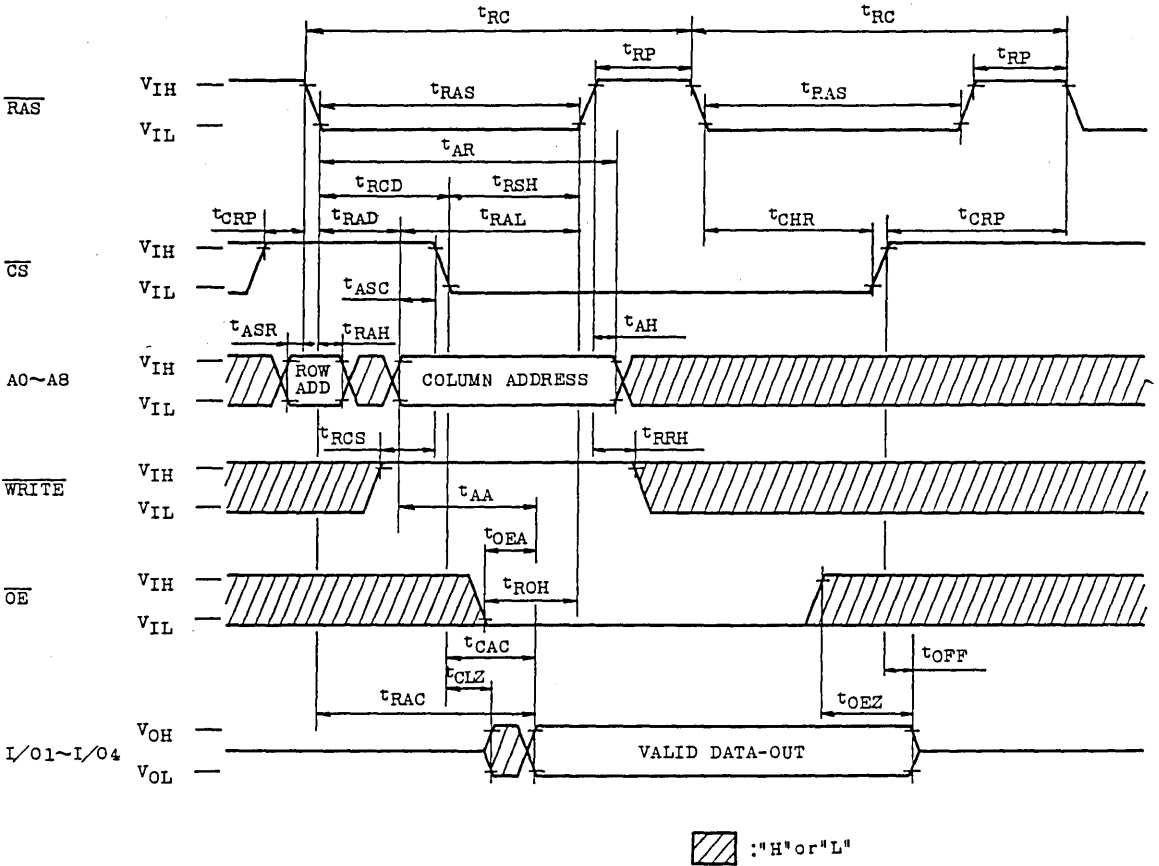
CS BEFORE RAS REFRESH CYCLE



Note:  $\overline{\text{WRITE}}$ ,  $\overline{\text{OE}}$ , A0 ~ A8 : "H" or "L"

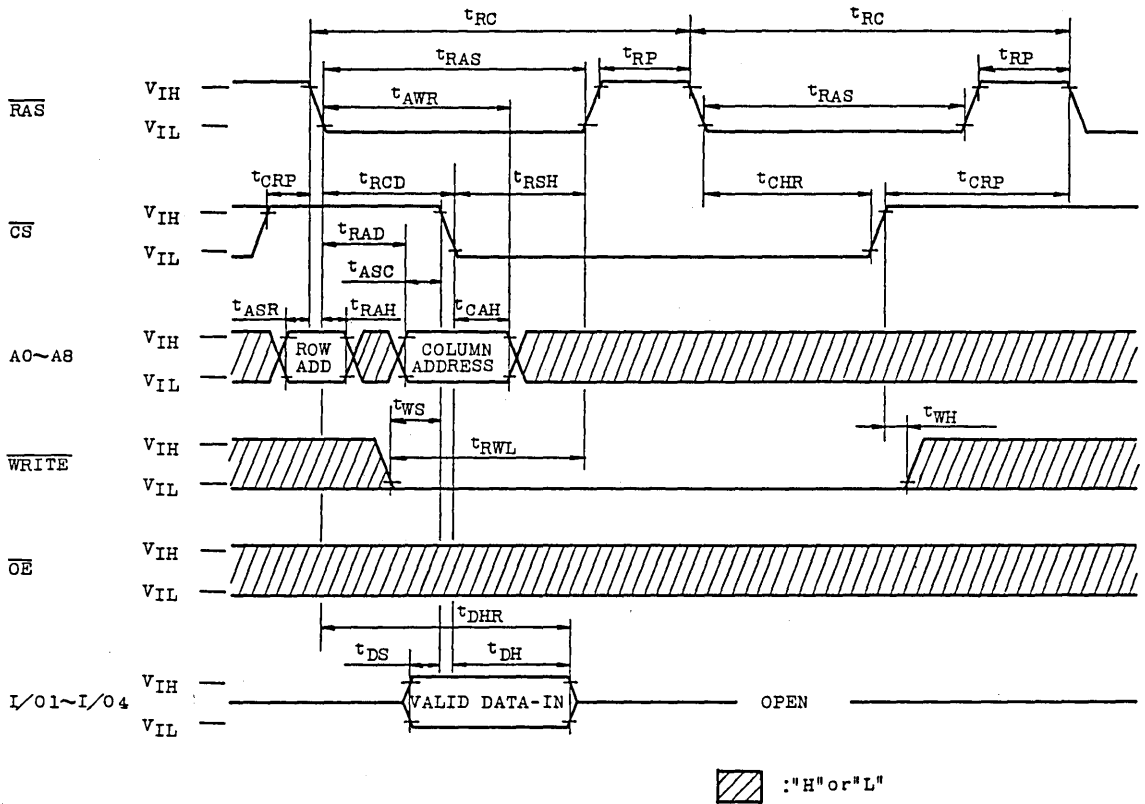
**TC514258P/J/Z-85, TC514258P/J/Z-10  
TC514258P/J/Z-12**

HIDDEN REFRESH CYCLE (READ)



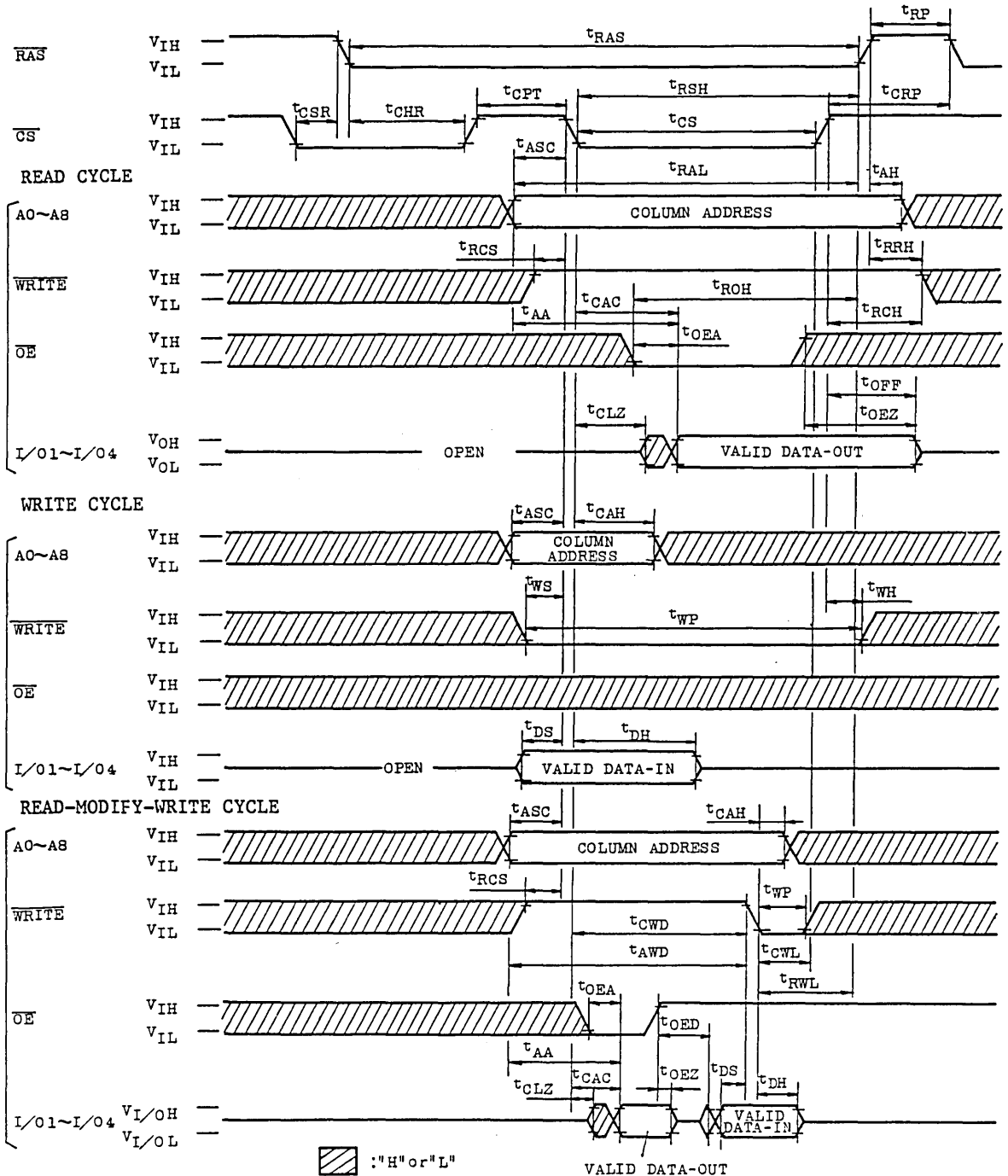
# TC514258P/J/Z-85, TC514258P/J/Z-10 TC514258P/J/Z-12

## HIDDEN REFRESH CYCLE (WRITE)



# TC514258P/J/Z-85, TC514258P/J/Z-10 TC514258P/J/Z-12

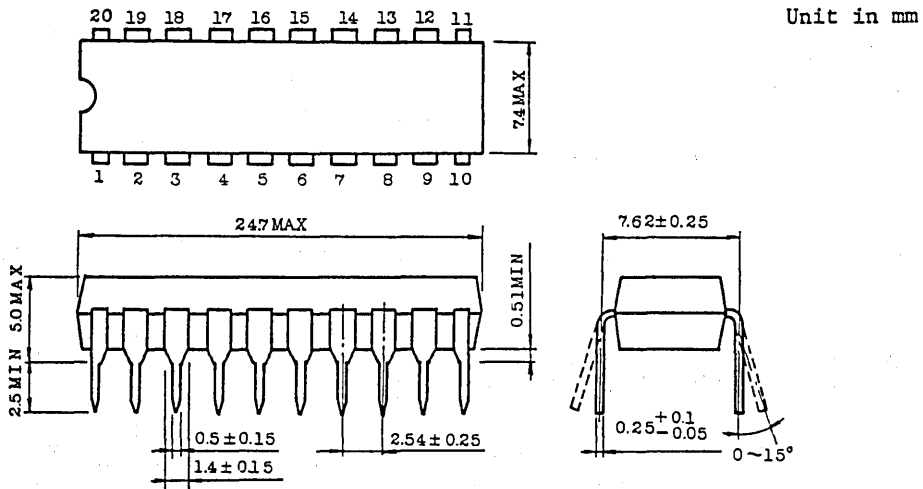
## CS BEFORE RAS REFRESH COUNTER TEST CYCLE



**TC514258P/J/Z-85, TC514258P/J/Z-10**  
**TC514258P/J/Z-12**

OUTLINE DRAWINGS

- Plastic DIP



Note: Each lead pitch is 2.54mm.

All leads are located within 0.25mm of their true longitudinal position with respect to No.1 and No.20 leads.

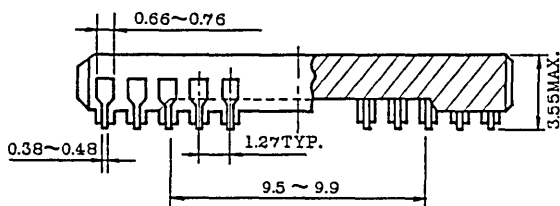
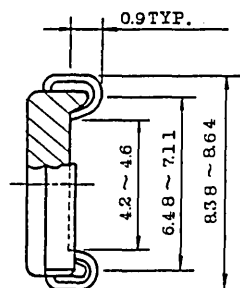
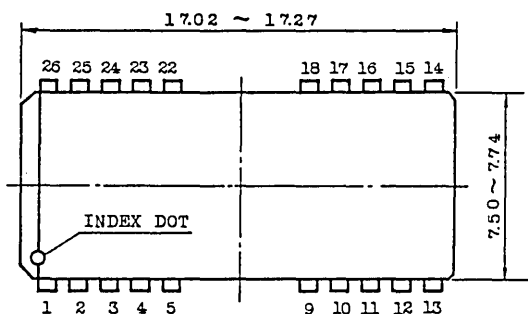
All dimensions are in millimeters.



# TC514258P/J/Z-85, TC514258P/J/Z-10 TC514258P/J/Z-12

• Plastic SOJ

Unit in mm

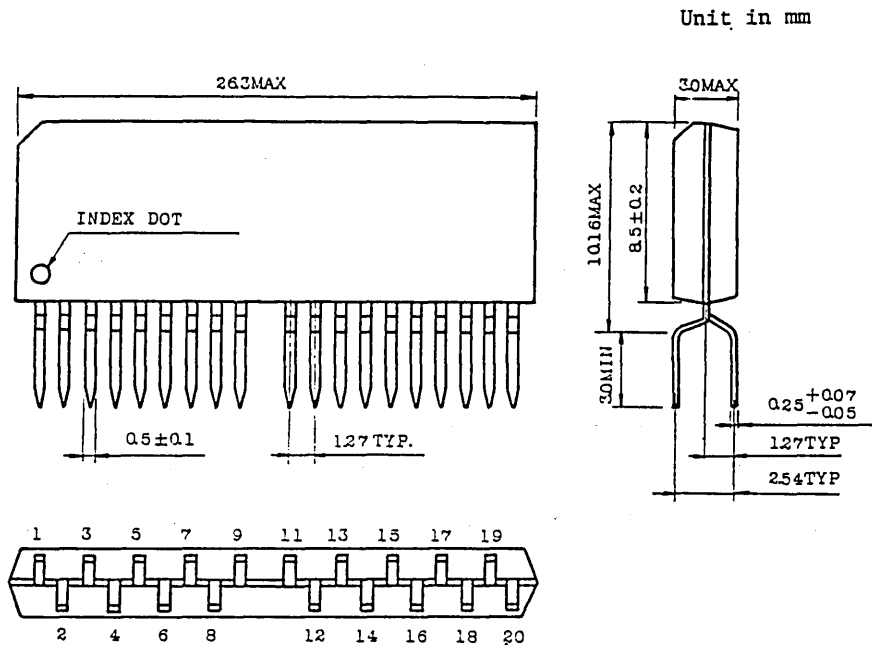


Note: Each lead pitch 1.27mm. All dimensions are in millimeters.

Toshiba does not assume any responsibility for use of any circuitry described; no circuit patent licenses are implied, and Toshiba reserves the right, at any time without notice, to change said circuitry.

**TC514258P/J/Z-85, TC514258P/J/Z-10  
TC514258P/J/Z-12**

• Plastic ZIP



Note: Each lead pitch is 1.27mm.

All dimensions are in millimeters.

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